Image may be representation.
See specs for product details.

SIJ458DP-T1-GE3

Hersteller-Teilenummer:	SIJ458DP-T1-GE3
Hersteller / Marke:	Electro-Films (EFI) / Vishay
Teil der Beschreibung:	MOSFET N-CH 30V 60A PPAK SO-8
Datenblätter:	SIJ458DP-T1-GE3.pdf
RoHs Status:	Bleifrei / RoHS-konform
Lagerzustand:	New original, Stock Available.
Liefern von:	Hong Kong
Versandweg:	DHL/Fedex/TNT/UPS/EMS

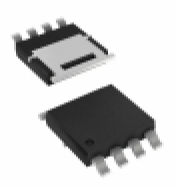
Spezifikationen

Teilenummer	SIJ458DP-T1-GE3
Hersteller	Electro-Films (EFI) / Vishay
Beschreibung	MOSFET N-CH 30V 60A PPAK SO-8
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	Require For Quote & Check Stock
VGS (th) (Max) @ Id	2.5V @ 250µA
Vgs (Max)	±20V
Technologie	MOSFET (Metal Oxide)
Supplier Device-Gehäuse	PowerPAK® SO-8
Serie	TrenchFET®
Rds On (Max) @ Id, Vgs	2.2 mOhm @ 20A, 10V
Verlustleistung (max)	5W (Ta), 69.4W (Tc)
Verpackung	Tape & Reel (TR)
Verpackung / Gehäuse	PowerPAK® SO-8
Andere Namen	SIJ458DP-T1-GE3TR
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Eingabekapazität (Ciss) (Max) @ Vds	4810pF @ 15V
Gate Charge (Qg) (Max) @ Vgs	122nC @ 10V
Typ FET	N-Channel
FET-Merkmal	-
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Drain-Source-Spannung (Vdss)	30V
detaillierte Beschreibung	N-Channel 30V 60A (Tc) 5W (Ta), 69.4W (Tc) Surface
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	60A (Tc)

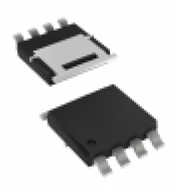
SIJ458DP-T1-GE3 Electronic Components ist ein 100% neues Original von YIC Distributor, SIJ458DP-T1-GE3-Datenblätter durchsuchen, PDF, Inventar bei Y-IC.com Online, SIJ458DP-T1-GE3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen bestellen. Versand per DHL / FedEx / TNT / UPS Express. Unterstützung der Zahlung mit telegrafischer Überweisung (T / T) oder PayPal.
RFQ SIJ458DP-T1-GE3 E-Mail: Info@Y-IC.com

Sie können auch interessiert sein:

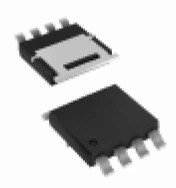
SIJ458DP-T1-E3
VISHAY
SIJ458DP-T1-E3 VISHAY



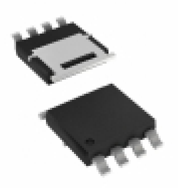
SIJ438DP-T1-GE3
Electro-Films (EFI) / Vishay
MOSFET N-CH 40V 80A PPAK SO-8L



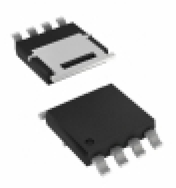
SIJ462DP-T1-GE3
Vishay Siliconix
MOSFET N-CH 60V 46.5A PPAK SO-8



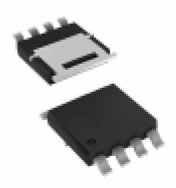
SIJ438DP-T1-GE3
Vishay Siliconix
MOSFET N-CH 40V 80A PPAK SO-8L



SIJ462DP-T1-GE3
Electro-Films (EFI) / Vishay
MOSFET N-CH 60V 46.5A PPAK SO-8



SIJ470DP-T1-GE3
Electro-Films (EFI) / Vishay
MOSFET N-CH 100V 58.8A PPAK SO-8



SIJ420DP-T1-GE3
Electro-Films (EFI) / Vishay
MOSFET N-CH 20V 50A PPAK SO-8

SIJ456DP-T1-GE3
VISHAY
VISHAY SOT669

Verwandtes Hot-Keyword

Mehr

- SIJ458DP-T1-GE3 Electro-Films (EFI) / Vishay
- SIJ458DP-T1-GE3 Datenblatt
- SIJ458DP-T1-GE3-Datenblätter
- SIJ458DP-T1-GE3 PDF
- Electro-Films (EFI) / Vishay SIJ458DP-T1-GE3
- SIJ458DP-T1-GE3 Electronic
- SIJ458DP-T1-GE3-Komponenten
- SIJ458DP-T1-GE3-Verteiler
- SIJ458DP-T1-GE3-Bild
- SIJ458DP-T1-GE3-Teil
- SIJ458DP-T1-GE3 Preis
- SIJ458DP-T1-GE3 Hersteller
- SIJ458DP-T1-GE3 Bild
- SIJ458DP-T1-GE3 Aktie
- SIJ458DP-T1-GE3 Inventar
- SIJ458DP-T1-GE3 Neu
- SIJ458DP-T1-GE3 Original
- SIJ458DP-T1-GE3 garantiert
- SIJ458DP-T1-GE3 RFQ
- SIJ458DP-T1-GE3 Online bestellen